NSN 5961-01-383-1978

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View Online at https://aerobasegroup.com/nsn/5961-01-383-1978 **Inclosure Material:** Metal and glass **Overall Length:** Between 0.790 inches and 0.800 inches **Overall Height:** Between 0.249 inches and 0.260 inches Overall Width: Between 0.535 inches and 0.545 inches **Mounting Facility Quantity: Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-254 **Mounting Method:** Unthreaded hole and terminal **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: -20.0 gate to source voltage and 20.0 gate to source voltage **Current Rating Per Characteristic:** -18.00 amperes regulator current and -72.00 amperes off-state current, peak **Power Rating Per Characteristic:** 4.0 watts on-state power dissipation **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Terminal Type And Quantity:** 3 uninsulated wire lead **Specification Data:** 81349-mil-s-19500/595 government specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0